

### 60V N-Channel MOSFET



TO-92

# **5**

### Pin Definition:

- 1. Source
- 2. Gate
- 3. Drain

### **PRODUCT SUMMARY**

| V <sub>DS</sub> (V) | $R_{DS(on)}(\Omega)$       | I <sub>D</sub> (mA) |
|---------------------|----------------------------|---------------------|
| 60                  | 5 @ V <sub>GS</sub> = 10V  | 100                 |
|                     | 5.5 @ V <sub>GS</sub> = 5V | 100                 |

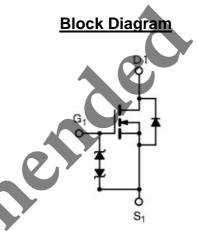
### **Features**

- Low On-Resistance
- ESD Protection
- High Speed Switching
- Low Voltage Drive

### **Ordering Information**

| Part No.         | Package | Packing      |
|------------------|---------|--------------|
| TSM2N7000KCT B0G | TO-92   | 1Kpcs / Bulk |
| TSM2N7000KCT A3G | TO-92   | 2Kpcs / Ammo |

Note: "G" denotes for Halogen Free



N-Channel MOSFET

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

| Parameter  | Symbol                            | Limit                             | Unit        |    |  |
|--|-----------------------------------|-----------------------------------|-------------|----|--|
| Drain-Source Voltage                             |                                   | V <sub>DS</sub>                   | 60          | V  |  |
| Gate-Source Voltage                              |                                   | $V_{GS}$                          | ±20         | V  |  |
| Drain Current                                    | Continuous @ T <sub>A</sub> =25°C | I <sub>D</sub>                    | 300         | mA |  |
|  | Pulsed                            | I <sub>DM</sub>                   | 700         |    |  |
| Drain Reverse Current                            | Continuous @ T <sub>A</sub> =25°C | I <sub>DR</sub>                   | 300         | mA |  |
|  | Pulsed                            | I <sub>DMR</sub>                  | 700         |    |  |
| Maximum Power Dissipation                        |                                   | P <sub>D</sub>                    | 400         | mW |  |
| Operating Junction Temperature                   |                                   | $T_J$                             | +150        | °C |  |
| Operating Junction and Storage Temperature Range |                                   | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C |  |

### **Thermal Performance**

| Parameter  | Symbol           | Limit | Unit |
|--|------------------|-------|------|
| Lead Temperature (1/8" from case)                    | $T_L$            | 10    | S    |
| Junction to Ambient Thermal Resistance (PCB mounted) | RΘ <sub>JA</sub> | 357   | °C/W |

### Notes:

- a. Pulse width limited by the Maximum junction temperature
- b. Surface Mounted on FR4 Board,  $t \le 5$  sec.



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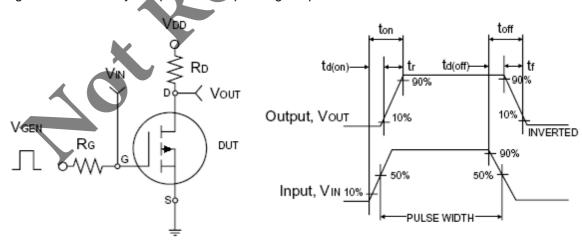


**Electrical Specifications** (Ta = 25°C, unless otherwise noted)

| Parameter                        | Conditions  | Symbol              | Min | Тур  | Max | Unit |
|----------------------------------|---|---------------------|-----|------|-----|------|
| Static                           |   |                     |     |      |     |      |
| Drain-Source Breakdown Voltage   | $V_{GS} = 0V, I_D = 10\mu A$                      | BV <sub>DSS</sub>   | 60  |      |     | V    |
| Gate Threshold Voltage           | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$              | V <sub>GS(TH)</sub> | 1.0 |      | 2.5 | V    |
| Gate Body Leakage                | $V_{GS} = \pm 20V, V_{DS} = 0V$                   | I <sub>GSS</sub>    |     |      | ±10 | uA   |
| Zero Gate Voltage Drain Current  | $V_{DS} = 60V, V_{GS} = 0V$                       | I <sub>DSS</sub>    |     |      | 1.0 | uA   |
| Desir Course On Otata Basistanaa | $V_{GS} = 10V, I_D = 100mA$                       |                     |     | 3    | 5   |      |
| Drain-Source On-State Resistance | $V_{GS} = 5V, I_D = 100mA$                        | $R_{DS(ON)}$        |     | 3.6  | 5.5 | Ω    |
| Forward Transconductance         | $V_{DS} = 10V, I_{D} = 200mA$                     | g <sub>fs</sub>     | 100 |      |     | mS   |
| Diode Forward Voltage            | $I_S = 300 \text{mA}, V_{GS} = 0 \text{V}$        | V <sub>SD</sub>     | (   | 0.9  | 1.2 | V    |
| Dynamic <sup>b</sup>             |   |                     |     |      |     |      |
| Total Gate Charge                | $V_{DS} = 10V, I_{D} = 250mA,$<br>$V_{GS} = 4.5V$ | Q <sub>g</sub>      |     | 0.4  |     | nC   |
| Input Capacitance                | V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V,      | C <sub>iss</sub>    |     | 7.32 |     |      |
| Output Capacitance               |   | Coss                |     | 3.42 |     | pF   |
| Reverse Transfer Capacitance     | f = 1.0MHz  | C <sub>rss</sub>    |     | 7.63 |     |      |
| Switching <sup>c</sup>           |   |                     |     |      |     |      |
| Turn-On Delay Time               | $V_{DD} = 30V, R_G = 10\Omega$                    | t <sub>d(on)</sub>  |     | 25   |     | 0    |
| Turn-Off Delay Time              | $I_D = 100 \text{mA}, V_{GEN} = 10 \text{V},$     | t <sub>d(off)</sub> |     | 35   |     | nS   |

### Notes:

- a. pulse test: PW ≤300µS, duty cycle ≤2% b. For DESIGN AID ONLY, not subject to production testing.
- b. Switching time is essentially independent of operating temperature.



Switching Test Circuit

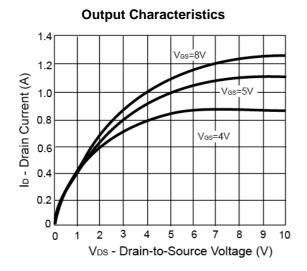
Switchin Waveforms

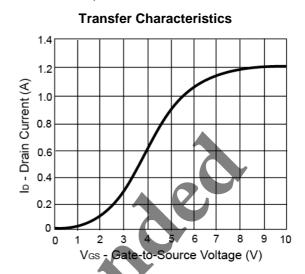


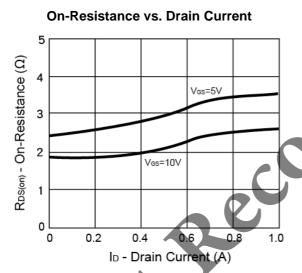
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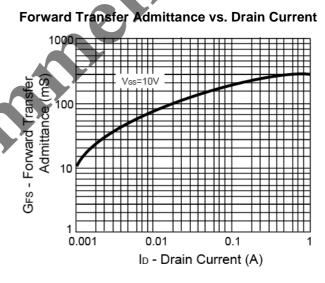


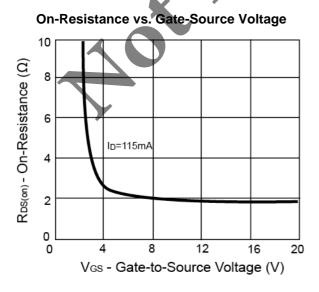
### **Electrical Characteristics Curve** (Ta = 25°C, unless otherwise noted)

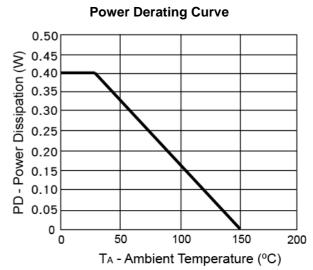










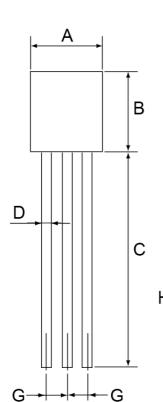




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# **TO-92 Mechanical Drawing**



| TO-92 DIMENSION |             |       |             |       |  |
|-----------------|-------------|-------|-------------|-------|--|
| DIM             | MILLIMETERS |       | INCHES      |       |  |
| DIIVI           | MIN         | MAX 🔺 | MIN         | MAX   |  |
| Α               | 4.30        | 4.70  | 0.169       | 0.185 |  |
| В               | 4.30        | 4.70  | 0.169       | 0.185 |  |
| С               | 13.53       | (typ) | 0.532 (typ) |       |  |
| D               | 0.39        | 0.49  | 0.015       | 0.019 |  |
| Е               | 1.18        | 1.28  | 0.046       | 0.050 |  |
| F               | 3.30        | 3.70  | 0.130       | 0.146 |  |
| G               | 1.27        | 1.31  | 0.050       | 0.051 |  |
| Н               | 0.33        | 0.43  | 0.013       | 0.017 |  |





Y = Year Code

**M** = Month Code for Halogen Free Product

 $\mathbf{O}$  =Jan  $\mathbf{P}$  =Feb  $\mathbf{Q}$  =Mar  $\mathbf{R}$  =Apr

S =May T =Jun U =Jul V =Aug

W =Sep X =Oct Y =Nov Z =Dec

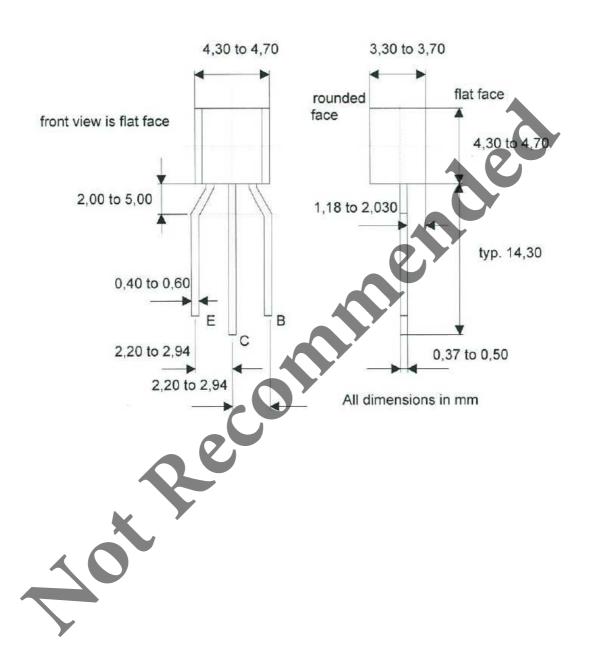
L = Lot Code



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# **TO-92 Ammo Pack Mechanical Drawing**









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